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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/621,852	07/16/2003	Yanjun Ma	SLA0815 (SMT324D)	1808	
75	590 03/29/2004		EXAMINER		
David C. Ripma			DIAZ, JOSE R		
Patent Counsel			ART UNIT	PAPER NUMBER	
	Sharp Laboratories of America, Inc. 5750 N.W. Pacific Rim Boulevard			2815	
Camas, WA	98607		DATE MAILED: 03/29/2004		

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)			
	10/621,852	MA ET AL.			
Office Action Summary	Examiner	Art Unit			
	José R Díaz	2815			
The MAILING DATE of this communication app Period for Reply	ears on the cover sheet with the	correspondence address			
A SHORTENED STATUTORY PERIOD FOR REPLY THE MAILING DATE OF THIS COMMUNICATION.  - Extensions of time may be available under the provisions of 37 CFR 1.13 after SIX (6) MONTHS from the mailing date of this communication.  - If the period for reply specified above is less than thirty (30) days, a reply tf NO period for reply is specified above, the maximum statutory period w - Failure to reply within the set or extended period for reply will, by statute, Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	36(a). In no event, however, may a reply be within the statutory minimum of thirty (30) dwill apply and will expire SIX (6) MONTHS from the application to become ABANDON	timely filed  ays will be considered timely.  m the mailing date of this communication.  IED (35 U.S.C. § 133).			
Status					
1) Responsive to communication(s) filed on 16 Ju	ıly 2003.				
•					
3) Since this application is in condition for allowar					
closed in accordance with the practice under E	closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.				
Disposition of Claims					
4) ☐ Claim(s) 16 and 17 is/are pending in the application 4a) Of the above claim(s) is/are withdray 5) ☐ Claim(s) is/are allowed.  6) ☐ Claim(s) 16 and 17 is/are rejected.  7) ☐ Claim(s) is/are objected to.  8) ☐ Claim(s) are subject to restriction and/or	wn from consideration.				
Application Papers					
9) The specification is objected to by the Examine	er.				
10) ☐ The drawing(s) filed on is/are: a) ☐ accepted or b) ☐ objected to by the Examiner.					
Applicant may not request that any objection to the	drawing(s) be held in abeyance. S	ee 37 CFR 1.85(a).			
Replacement drawing sheet(s) including the correct 11) The oath or declaration is objected to by the Ex					
Priority under 35 U.S.C. § 119					
<ul> <li>12) Acknowledgment is made of a claim for foreign</li> <li>a) All b) Some * c) None of:</li> <li>1. Certified copies of the priority document</li> <li>2. Certified copies of the priority document</li> <li>3. Copies of the certified copies of the priority application from the International Bureau</li> <li>* See the attached detailed Office action for a list</li> </ul>	s have been received. s have been received in Applica rity documents have been recei u (PCT Rule 17.2(a)).	ation No ved in this National Stage			
Attachment(s)					
1) Notice of References Cited (PTO-892)	4) Interview Summa				
Notice of Draftsperson's Patent Drawing Review (PTO-948)     Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08)	Paper No(s)/Mail 5) Notice of Informa	Date I Patent Application (PTO-152)			
Paper No(s)/Mail Date	6) Other:	•			

## **DETAILED ACTION**

## Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

Claims 16-17 are rejected under 35 U.S.C. 102(b) as being anticipated by Watabe et al. (US Pat. No. 5,146,291).

Regarding claim 16, Watabe et al. teaches a sub-micron MOS transistor comprising: a substrate (2) (see fig. 1); and an active region (portion of the substrate as shown in fig 1.), including a gate region (4a) (see fig. 1) having a length of less than one micron (i.e. about 0.5 μm, see col. 7, lines 37-40 and 45-48, and col. 8, lines 23-24); a source region (5a) including a LDD source region (5b) (see fig. 1); and a drain region (6a) including a LDD drain region (6b) (see fig. 1); wherein the ion concentration in said source region (5a) and in said drain region (6a) is between about 1 x 10<sup>20</sup> to 1 x 10<sup>21</sup> cm<sup>-3</sup> (see col. 17, lines 22-25), and wherein the ion concentration in said LDD source region (5b) and in said LDD drain region (6b) is between about 5 x10<sup>18</sup> to 5 x 10<sup>19</sup> cm<sup>-3</sup> (see col. 17, lines2-5).

Regarding claim 17, Watabe et al. further teaches an insulating oxide layer (3), a source electrode (12), a gate electrode ( $V_g$ ), and a drain electrode (13) (see figs. 1 and 2B).

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## Correspondence

Any inquiry concerning this communication or earlier communications from the examiner should be directed to José R Díaz whose telephone number is (571) 272-1727. The examiner can normally be reached on 9:00-5:00 Monday through Friday.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Tom Thomas can be reached on (571) 272-1664. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

JRD 3/21/04

GEORGE ECKERT
PRIMARY EXAMINER